



### **150V NPN SILICON LOW SATURATION TRANSISTOR IN SOT23**

#### **Features**

- $V_{CEO} = 150V$ .
- $I_C = 1A$ •
- 625mW Power dissipation •
- Low Equivalent On Resistance .
- Low Saturation Voltage
- hFE characterised up to 3.0A
- Lead, Halogen and Antimony Free, RoHS Compliant (Note 1)
- "Green" Devices (Note 2)

#### **Mechanical Data**

- Case: SOT-23 •
- Case material: molded Plastic. "Green" molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.008 grams (Approximate)

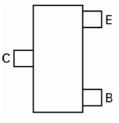
#### Applications

- **DC-DC Modules**
- **Power Management Functions**
- Motor control and drive functions



SOT-23

Device symbol



Pinout - top view

# Ordering Information (Note 3)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FMMT625TA	625	7	8mm embossed	3000 units

1. No purposefully added lead.

2. Devices with the PID number starting from PID0155145 are 'Green' products. Halogen and Antimony Free.

3. Diodes Incorporated's "Green" Policy can be found on our website at https://www.diodes.com.

## **Marking Information**

Notes:







#### **Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	150	V
Collector-Emitter Voltage	V <sub>CEO</sub>	150	V
Emitter-Base Voltage	V <sub>EBO</sub>	5	V
Continuous Collector Current	Ic	1	А
Peak Pulse Current (Note 4)	I <sub>CM</sub>	3	А
Base Current	IB	500	mA

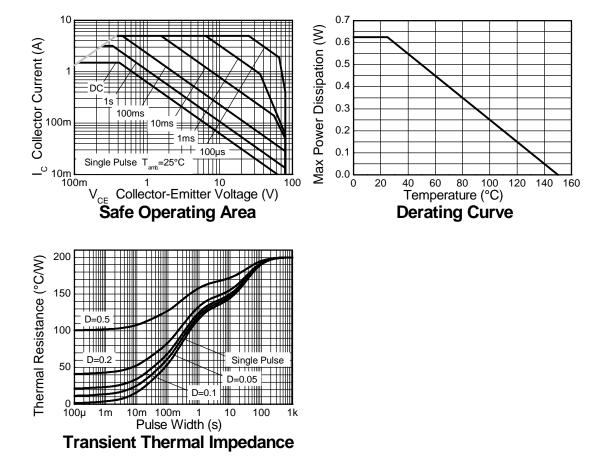
## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation at $T_A = 25^{\circ}C$ (Note 5)	PD	625	mW
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes: 4. Measured under pulsed conditions. Pulse width =  $300\mu$ s. Duty cycle  $\leq 2\%$ .

5. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions

# **Thermal Characteristics and Derating information**







# Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

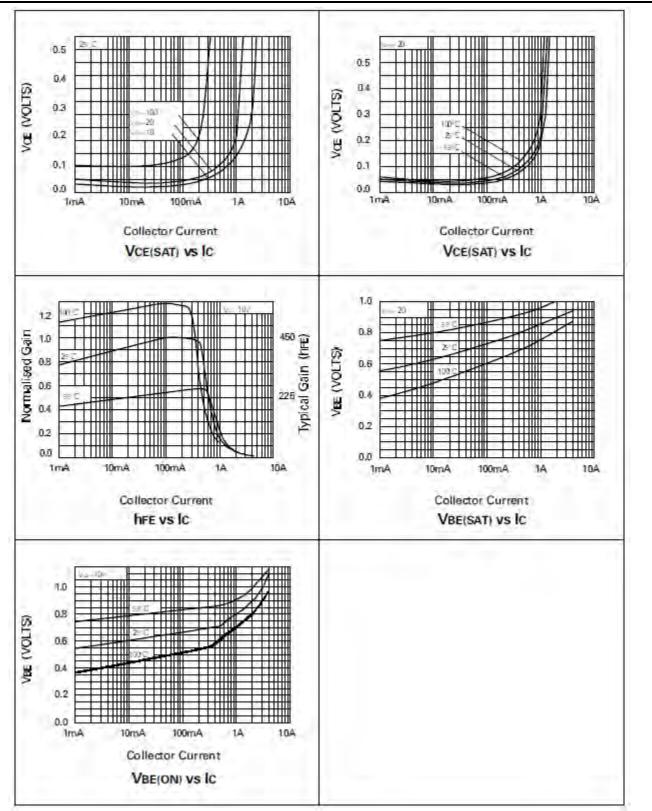
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
		150	300		V	
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>			-	-	$I_{\rm C} = 100\mu A$
Collector-Emitter Breakdown Voltage (Note 6)	V <sub>(BR)CEO</sub>	150	175	-	V	$I_{\rm C} = 10 {\rm mA}$
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	5	8.3	-	V	I <sub>E</sub> = 100μA
Collector Cut-off Current	I <sub>CBO</sub>	-	-	100	nA	V <sub>CB</sub> =130V
Emitter Cut-off Current	I <sub>EBO</sub>	-	-	100	nA	$V_{EB} = 4V$
Collector Emitter Cut-off Current	I <sub>CES</sub>	-	-	100	nA	V <sub>CES</sub> =130V
Static Forward Current Transfer Ratio (Note 6)	h <sub>FE</sub>	200 300 30 -	400 450 45 15	- - -	-	$\begin{split} I_{C} &= 10 \text{mA}, \ V_{CE} = 10 \text{V} \\ I_{C} &= 200 \text{mA}, \ V_{CE} = 10 \text{V} \\ I_{C} &= 1\text{A}, \ V_{CE} = 10 \text{V} \\ I_{C} &= 3\text{A}, \ V_{CE} = 10 \text{V} \end{split}$
Collector-Emitter Saturation Voltage (Note 6)	V <sub>CE(sat)</sub>	-	26 110 180	50 200 300	mV	$I_{C}$ =0.1A, $I_{B}$ = 10mA $I_{C}$ =0.1A, $I_{B}$ = 1mA $I_{C}$ =1A, $I_{B}$ = 50mA
Base-Emitter Saturation Voltage (Note 6)	V <sub>BE(sat)</sub>	-	0.85	1.0	V	$I_{C} = 1A, I_{B} = 50mA$
Base-Emitter Saturation Voltage (Note 6)	V <sub>BE(on)</sub>	-	0.74	1.0	V	I <sub>C</sub> =1A, V <sub>CE</sub> = 10V
Transition Frequency	fT	100	135	-	MHz	$I_{C} = 50 \text{mA}, V_{CE} = 10 \text{V},$ f=100MHz
Collector Output Capacitance	C <sub>obo</sub>	-	6	10	pF	V <sub>CB</sub> = 10V, f=1MHz
Turn-On Time	t <sub>(on)</sub>	-	160	-	ns	$V_{CC} = 50V, I_C = 500mA,$
Turn-Off Time	t <sub>(off)</sub>	-	1500	-	ns	$I_{B1} = -I_{B2} = 50 \text{mA}$

6. Measured under pulsed conditions. Pulse width = 300 $\mu s.$  Duty cycle  $\leq 2\%$ Notes:





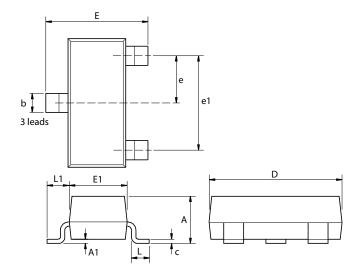
# **Typical Characteristics**







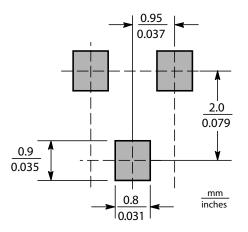
# **Package Outline Dimensions**



Dim.	Millimeters		Inches		Dim.	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
А	-	1.12	-	0.044	e1	1.90 NOM		0.075 NOM	
A1	0.01	0.10	0.0004	0.004	E	2.10	2.64	0.083	0.104
b	0.30	0.50	0.012	0.020	E1	1.20	1.40	0.047	0.055
с	0.085	0.20	0.003	0.008	L	0.25	0.60	0.0098	0.0236
D	2.80	3.04	0.110	0.120	L1	0.45	0.62	0.018	0.024
е	0.95 NOM		0.037	NOM	-	-	-	-	-

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

# Suggested Pad Layout







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